Memory Architectures

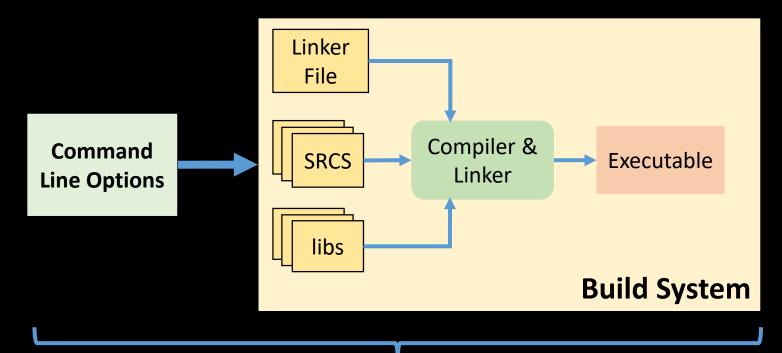
Embedded Software Essentials

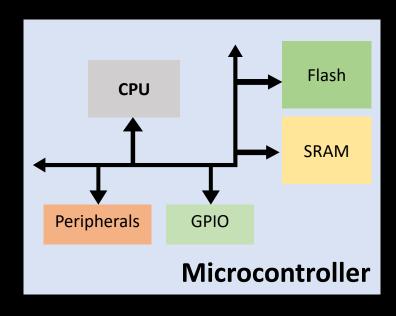
C1M3V2



Programing Embedded Systems

 Executable Program consists of program code and program data compiled for a particular architecture and platform



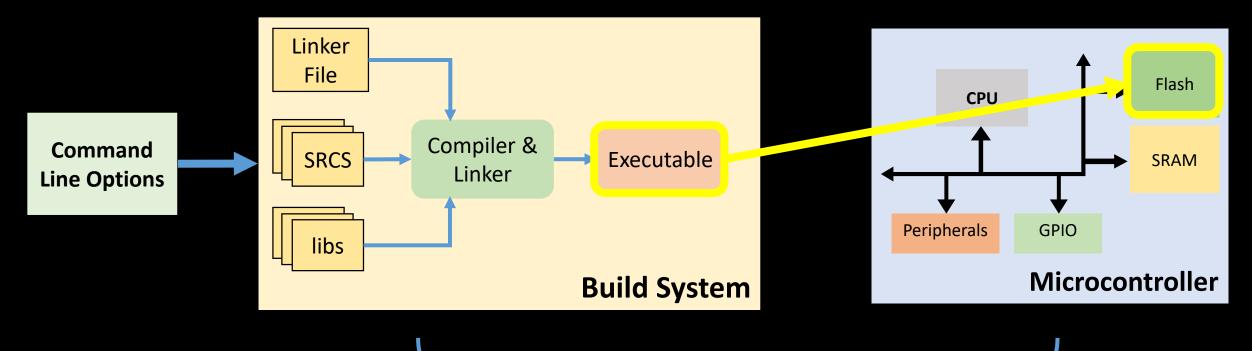




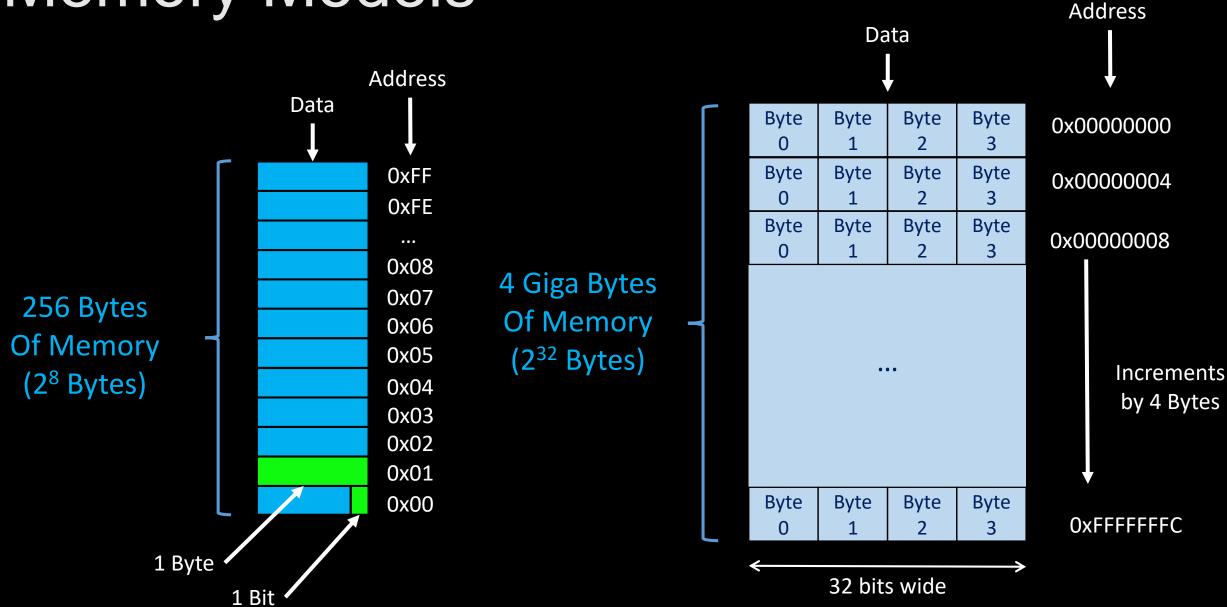


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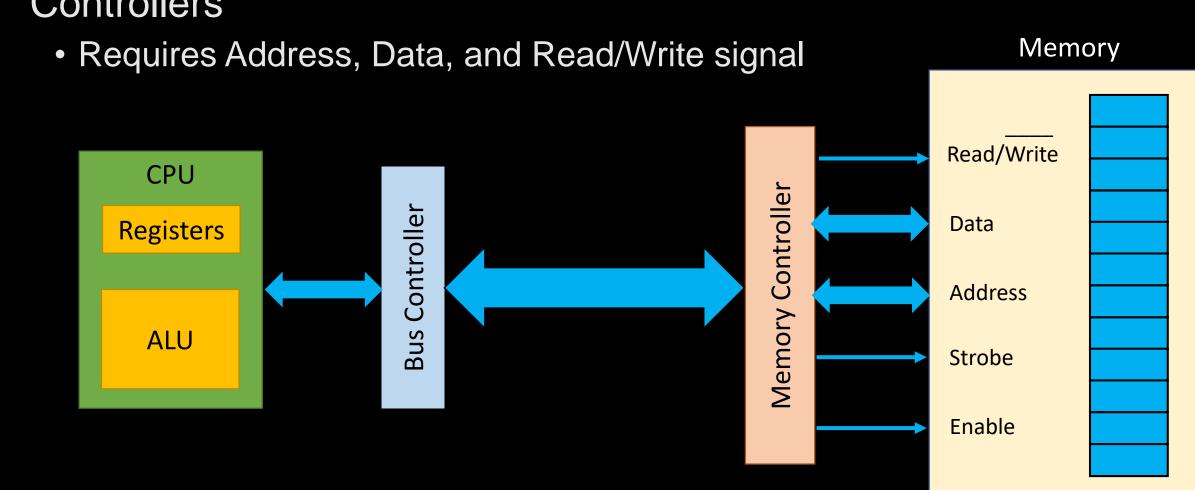


Memory Models



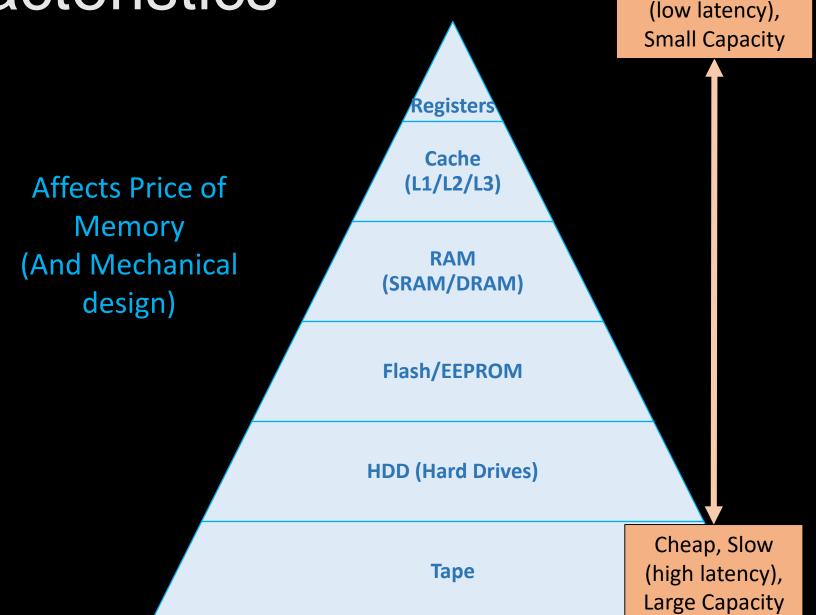
Memory Interfaces

 CPU Reads or Writes data to Memory through Bus and Memory Controllers



Memory Characteristics

- Capacity
- Volatility
- Access
- Power Consumption
- Latency
- Durability
- Transaction Size



Expensive, Fast

Capacity

- Capacity: the amount of storage a memory can hold
 - Embedded Systems do <u>NOT</u> need a lot of memory, they need optimized performance

- Increasing capacity increases the complexity of design and size
 - Physical size and connection circuitry (potentially)

You want to <u>LIMIT</u> size, power & cost of system

```
Capacity = Size = Power = Cost

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Volatility

- Volatility: The ability for memory to hold data without power
 - Volatile Memory Loses data when power removed
 - Non-Volatile Retains data when power is removed

Volatile Memories:

- SRAM
- DRAM
- SDRAM
- Register (most)

Non-Volatile Memories:

- ROM/PROM/EPROM/EEPROM
- Flash
- Disk¹
- Tape¹



Many pros and cons to the different technologies

¹Not used in modern design



Volatility

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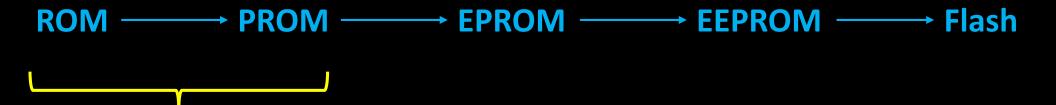
Non-Volatile Memories:

Exhibits <u>endurance</u> issues, limited number of write-erase cycles



• Endurance: Non-volatile semiconductor memories have a limited number of write-erase cycles before failure

Programmable Memory Evolution:



Programmable ONLY once



• Endurance: Non-volatile semiconductor memories have a limited number of write-erase cycles before failure

Programmable Memory Evolution:



Erasable (UV exposure) and Programmable Multiple times



• Endurance: Non-volatile semiconductor memories have a limited number of write-erase cycles before failure

Programmable Memory Evolution:



Electrically Erasable and Programmable Many times



 Endurance: Non-volatile semiconductor memories have a limited number of write-erase cycles before failure

Programmable Memory Evolution:

Flash has an Endurance lasting 10,000 to 100,000+ Write-Erase Cycles



Memory Access

- Random Access: Allows for access to any part of memory given the address of that location
 - Random Access Memory (RAM) SRAM/DRAM

- Access Security: Require credentials to Read/Write parts of memory
 - Read-Only Memory (ROM) No ability to write without extra permissions or process



Memory Comparison

SRAM

- Simple Read/Write Process
- No Access Security
- Byte level read/write
- Volatile
- No write/erase endurance issues

Flash (as Read-Only Memory)

- Complex Read/Write process
- Secure Write Access
- Page level read/write
- Non-Volatile
- Endurance issues (Limited Write/erase cycles)



Latency

 <u>Latency</u>: Time it takes for memory to respond to a read/write request

- Code and Data need to be read/written to memory
 - Assembly Instructions are read
 - Instruction operands need to be read
 - Instruction results need to written

These read/write operations take a certain amount of time

 Any data read/written interacts with the CPU, Bus Controller, Bus, memory controller, & memory

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